

ZXTD6717E6
COMPLEMENTARY 15V NPN & 12V PNP LOW SATURATION TRANSISTORS IN SOT26
Features and Benefits

- $P_d = 1.1W$ in SOT26 Package
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

NPN Transistor

- $BV_{CEO} > 15V$
- $I_C = 1.5A$ Continuous Collector Current
- Low Saturation Voltage (100mV max @ 1A)
- $R_{SAT} = 135m\Omega$ @ 1.5A for a Low Equivalent On-Resistance

PNP Transistor

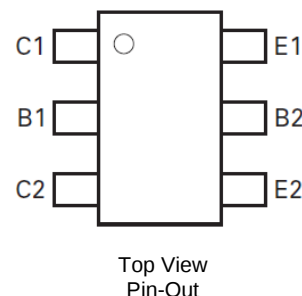
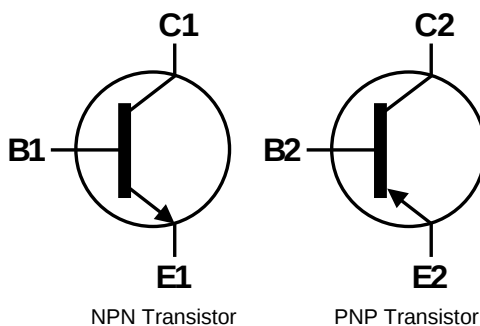
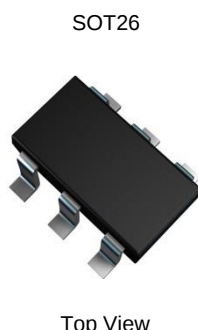
- $BV_{CEO} > -12V$
- $I_C = -1.25A$ Continuous Collector Current
- Low Saturation Voltage (-140mV max @ -1A)
- $R_{SAT} = 150m\Omega$ @ 1.2A for a Low Equivalent On-Resistance

Mechanical Data

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.015 grams (Approximate)

Applications

- Efficient Driving Functions including Motors, Lamps, Relays and Solenoids
- High Output Current Switches

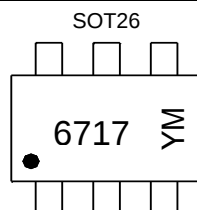


Device Symbol

Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTD6717E6TA	AEC-Q101	6717	7	8	3,000
ZXTD6717E6QTA	Automotive	6717	7	8	3,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
 5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information


6717 = Product Type Marking Code
 YM = Date Code Marking
 Y or $\bar{Y}$ = Year (ex: C = 2015)
 M or $\bar{M}$ = Month (ex: 9 = September)

Date Code Key

Year	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025
Code	C	D	E	F	G	H	I	J	K	L	M

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

ZXTD6717E6

Document Number: DS33653 Rev: 4 - 2

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March 2015

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NPN - Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	15	V
Collector-Emitter Voltage	V _{CEO}	15	V
Emitter-Base Voltage	V _{EBO}	7	V
Peak Pulse Current	I _{CM}	5	A
Continuous Collector Current	I _C	1.5	A
Base Current	I _B	200	mA

PNP - Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-12	V
Collector-Emitter Voltage	V _{CEO}	-12	V
Emitter-Base Voltage	V _{EBO}	-7	V
Peak Pulse Current	I _{CM}	-3	A
Continuous Collector Current	I _C	-1.25	A
Base Current	I _B	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	1.1	W
Linear Derating Factor		8.8	
		1.7	
		13.6	mW/°C
Thermal Resistance, Junction to Ambient	R _{θJA}	125	°C/W
		45	
Thermal Resistance, Junction to Lead	R _{θJL}	95	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

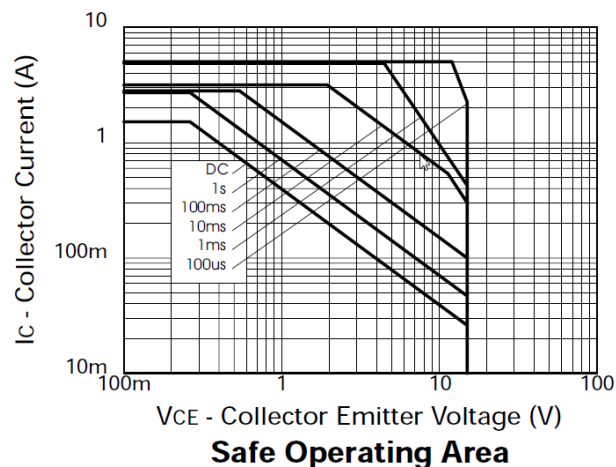
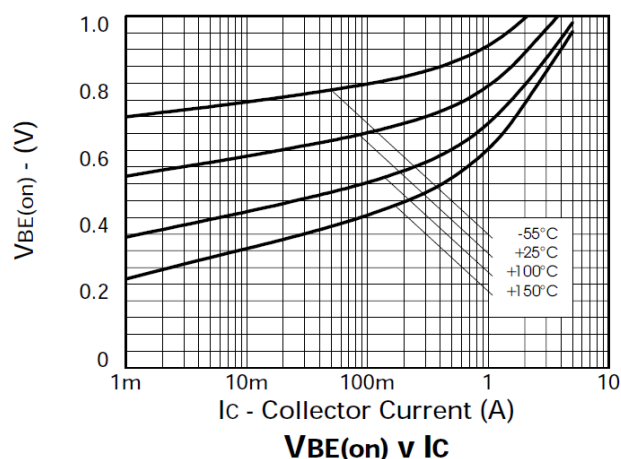
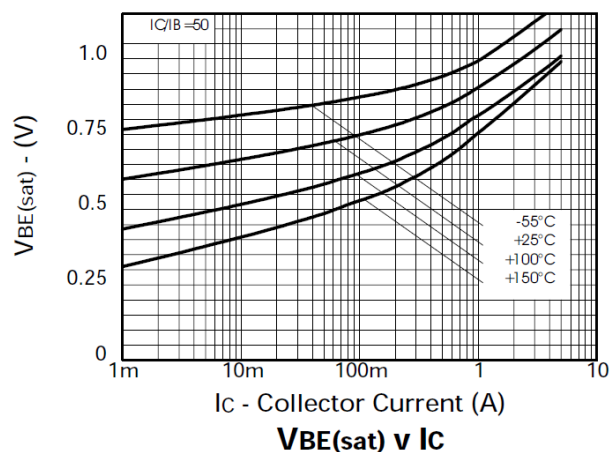
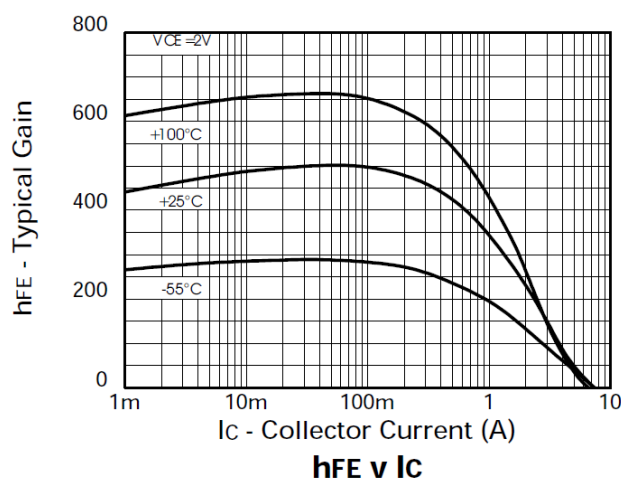
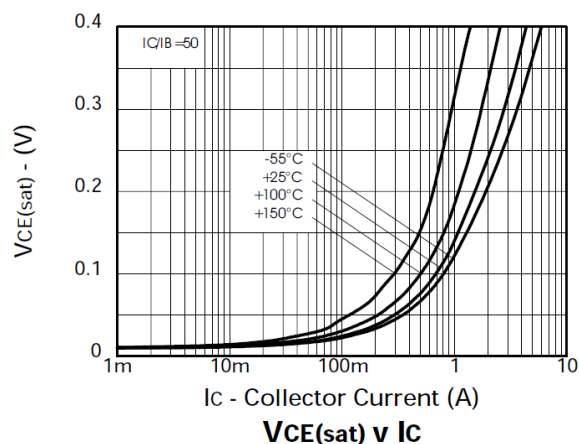
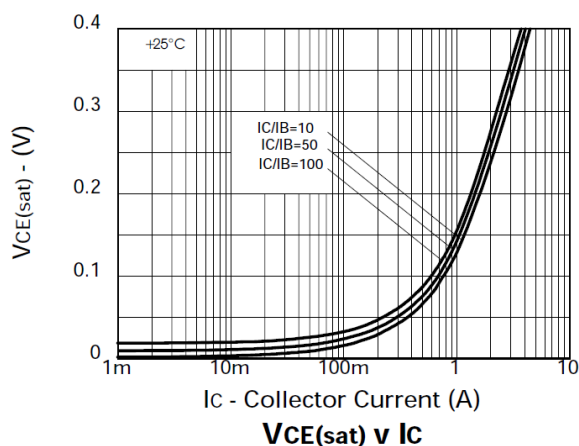
- Notes:
6. For a device mounted with the collector lead on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; the device is measured under still air conditions whilst operating in a steady-state. Two active dice running at equal power with heatsink split 50% to each collector.
 7. Same as Note 6, except the device is measured at t < 5 seconds.
 8. Thermal resistance from junction to solder-point (at the end of the collector lead).
 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

NPN - Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	15	—	—	V	I _C = 100μA, I _E = 0
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	15	—	—	V	I _C = 10mA, I _B = 0
Emitter-Base Breakdown Voltage	BV _{EBO}	7	—	—	V	I _E = 100μA, I _C = 0
Collector Cut-Off Current	I _{CBO}	—	<-1	10	nA	V _{CB} = 10V
Emitter Cut-Off Current	I _{EBO}	—	<-1	10	nA	V _{EB} = 5.6
Emitter Cut-Off Current	I _{CES}	—	<-1	10	nA	V _{CE} = 10V
ON CHARACTERISTICS (Note 10)						
DC Current Gain	h _{FE}	200	420	—	—	I _C = 10mA, V _{CE} = 2V
		300	450	—		I _C = 100mA, V _{CE} = 2V
		250	390	—		I _C = 500mA, V _{CE} = 2V
		200	300	—		I _C = 1A, V _{CE} = 2V
		75	150	—		I _C = 3A, V _{CE} = 2V
		30	75	—		I _C = 5A, V _{CE} = 2V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	16.5	20	mV	I _C = 100mA, I _B = 10mA
			40	55	mV	I _C = 250mA, I _B = 10mA
			75	100	mV	I _C = 500mA, I _B = 10mA
			150	200	mV	I _C = 1A, I _B = 10mA
			205	245	mV	I _C = 1.5A, I _B = 20mA
Base-Emitter Saturation Voltage	V _{BE(sat)}	—	0.93	1.10	V	I _C = 1.5A, I _B = 20mA
Base-Emitter Turn-On Voltage	V _{BE(on)}	—	0.865	1.10	V	I _C = 1.5A, V _{CE} = 2V
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C _{obo}	—	15	—	pF	V _{CB} = 10V, f = 1.0MHz
Current Gain Bandwidth Product	f _T	—	180	—	MHz	I _C = 50mA, V _{CE} = 10V f = 100MHz
SWITCHING CHARACTERISTICS						
Turn-On Time	t _{on}	—	50	—	ns	I _C = 1A, V _{CC} = 10V
Turn-Off Time	t _{off}	—	250	—	ns	I _{B1} = -I _{B2} = 100mA

Note: 10. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

NPN - Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

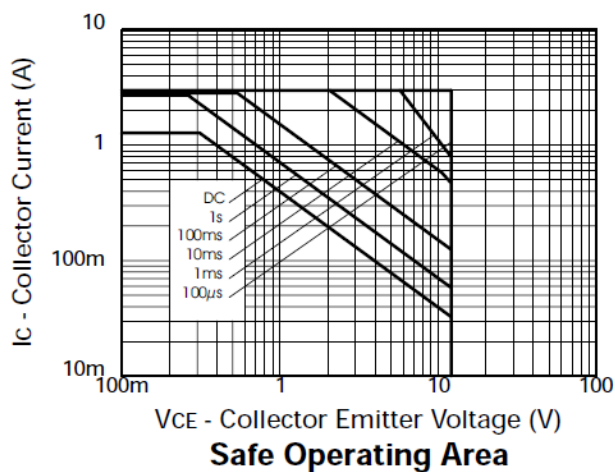
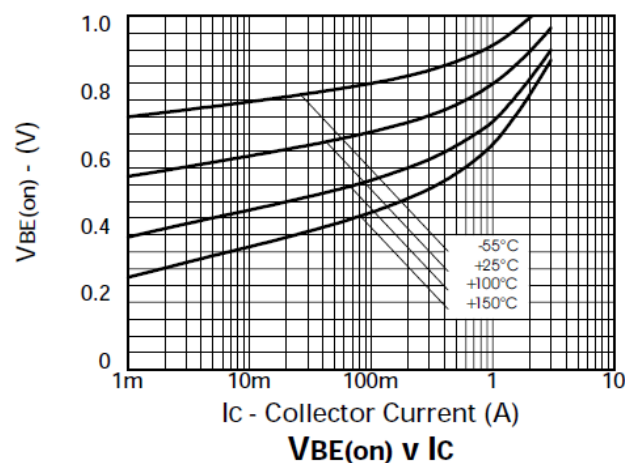
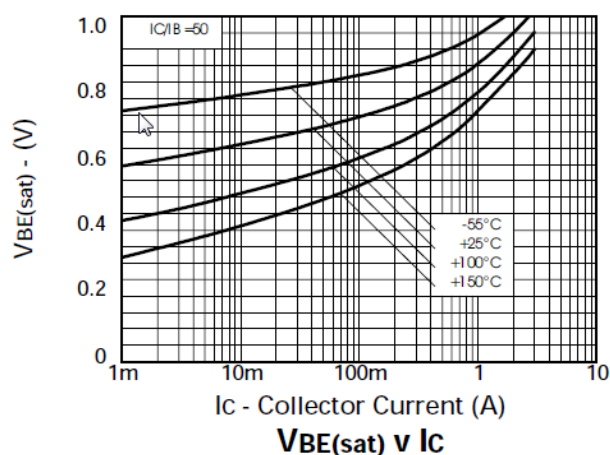
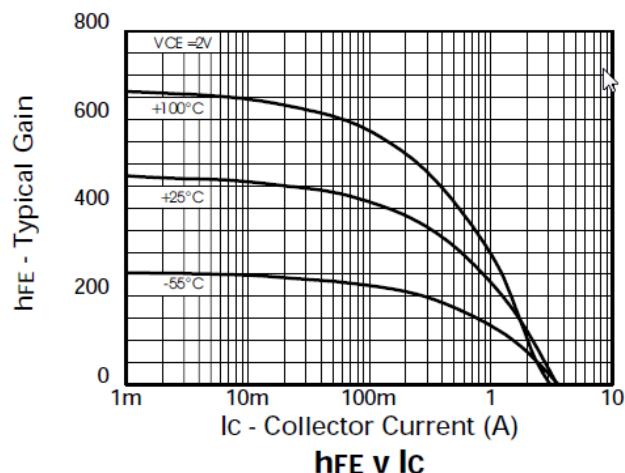
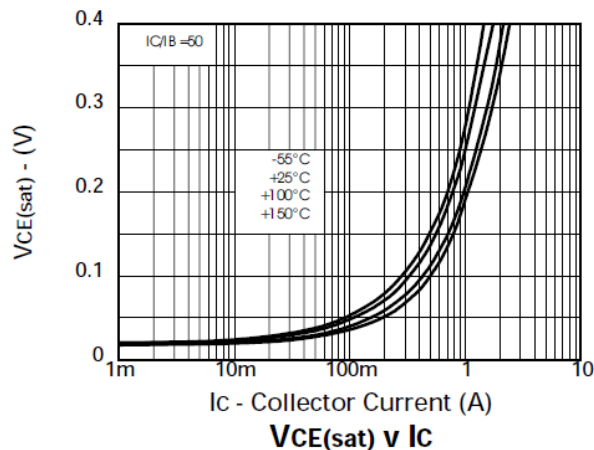
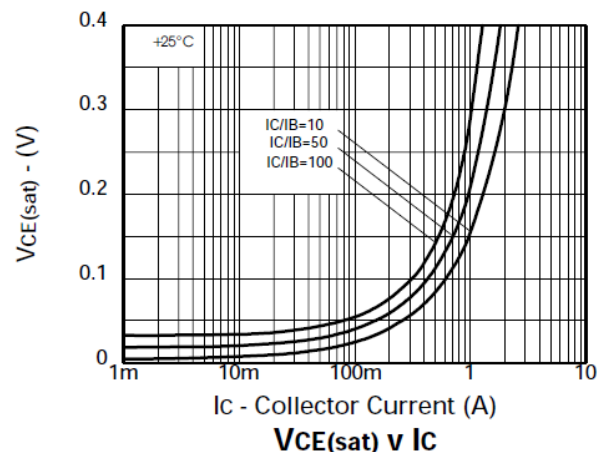


PNP - Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	-12	—	—	V	I _C = -100μA, I _E = 0
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	-12	—	—	V	I _C = -10mA, I _B = 0
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	—	—	V	I _E = -100μA, I _C = 0
Collector Cut-Off Current	I _{CBO}	—	<-1	-10	nA	V _{CB} = -10V
Emitter Cut-Off Current	I _{EBO}	—	<-1	-10	nA	V _{EB} = -5.6V
Emitter Cut-Off Current	I _{CES}	—	<-1	-10	nA	V _{CE} = -10V
ON CHARACTERISTICS (Note 11)						
DC Current Gain	h _{FE}	300	490	—	—	I _C = -10mA, V _{CE} = -2V
		300	450	—		I _C = -100mA, V _{CE} = -2V
		200	340	—		I _C = -500mA, V _{CE} = -2V
		125	250	—		I _C = -1.25A, V _{CE} = -2V
		75	140	—		I _C = -2A, V _{CE} = -2V
		30	80	—		I _C = -3A, V _{CE} = -2V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	-25	-40	mV	I _C = -100mA, I _B = -10mA
			-55	-100	mV	I _C = -250mA, I _B = -10mA
			-110	-175	mV	I _C = -500mA, I _B = -10mA
			-160	-215	mV	I _C = -1A, I _B = -50mA
			-185	-240	mV	I _C = -1.25A, I _B = -100mA
			—	—	—	I _C = -1.25A, I _B = -100mA
Base-Emitter Saturation Voltage	V _{BE(sat)}	—	-0.99	-1.10	V	I _C = -1.25A, I _B = -100mA
Base-Emitter Turn-On Voltage	V _{BE(on)}	—	-0.85	-1.0	V	I _C = -1.25A, V _{CE} = -2V
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C _{obo}	—	15	—	pF	V _{CB} = -10V, f = 1.0MHz
Current Gain Bandwidth Product	f _T	—	220	—	MHz	I _C = -50mA, V _{CE} = -10V f = 100MHz
SWITCHING CHARACTERISTICS						
Turn-On Time	t _{on}	—	50	—	ns	I _C = -1A, V _{CC} = -10V
Turn-Off Time	t _{off}	—	135	—	ns	I _{B1} = -I _{B2} = -100mA

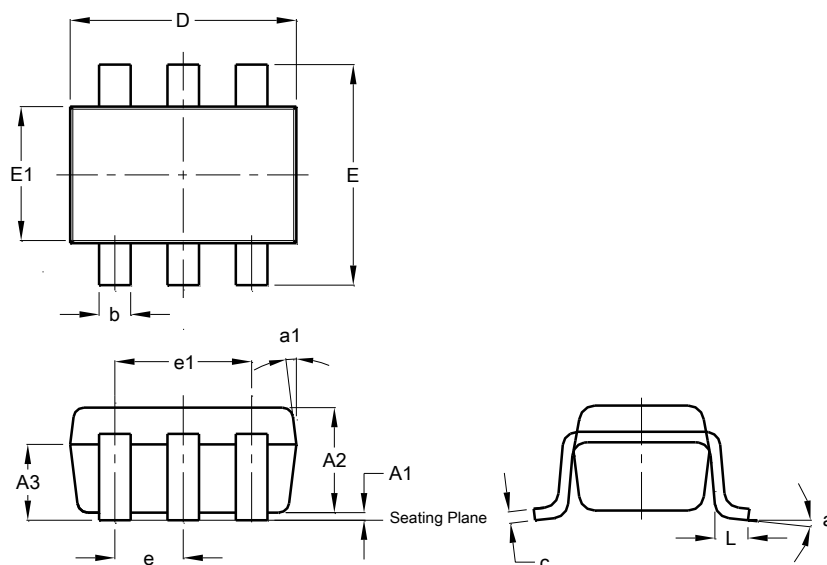
Note: 11. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

PNP - Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Package Outline Dimensions

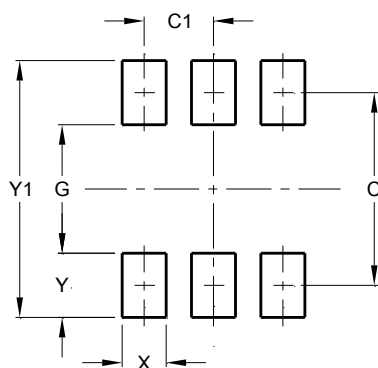
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT26			
Dim	Min	Max	Typ
A1	0.013	0.10	0.05
A2	1.00	1.30	1.10
A3	0.70	0.80	0.75
b	0.35	0.50	0.38
c	0.10	0.20	0.15
D	2.90	3.10	3.00
e	-	-	0.95
e1	-	-	1.90
E	2.70	3.00	2.80
E1	1.50	1.70	1.60
L	0.35	0.55	0.40
a	-	-	8°
a1	-	-	7°
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	2.40
C1	0.95
G	1.60
X	0.55
Y	0.80
Y1	3.20

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